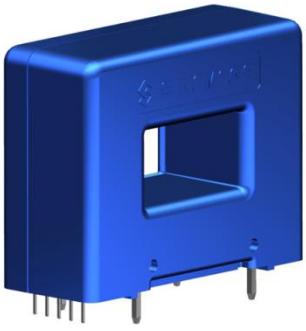
CURRENT SENSOR

PRODUCT SERIES: STB-LA/Zx

PRODUCT PART NUMBER: STB-100LA/Z, STB-100LA/ZN
STB-150LA/Z, STB-150LA/ZN
STB-200LA/Z, STB-200LA/ZN

VERSION: Ver 5.2



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Web site: www.sinomags.com

CONTENT

1. Description

STB-LA/Z series current sensors are based on close loop principle with TMR technology. The sensor can detect the current with DC, AC, pulse and irregular wave shape.

Typical application

- Solar inverter
- Uninterruptible Power Supplies (UPS)
- Variable frequency converter
- Direct-current dynamo
- Switched model power supplies (SMPS)

General parameters

Parameter	Symbol	Unit	Value	Remark
Working temperature	T_A	℃	-40 ~ 85	
Storage temperature	T_stg	℃	-40 ~ 85	
Limit temperature of primary conductor	T_LP	℃	105	STB-xxxLA/Z
Mass	m	g	59	STB-xxxLA/ZN
Mass	m	g	86	STB-xxxLA/Z

Absolute parameters

Parameters	Symbol	Unit	Value
Supply voltage	Vcc_max	V	6
Maximum primary current	I_p_max	A	10*I_pn
ESD rating (HBM)	U_ESD_HBM	kV	4

Remark: the unrecoverable damage may occur when the product works on the conditions over the absolute maximum ratings. Long-time working on the absolute maximum ratings may cause the degradation on performance and reliability.

Isolation parameters

Parameter	Symbol	Unit	Value	Remark
RMS voltage for AC test 50Hz/1 min	Ud	kV	4	
Impulse withstand voltage 1.2/50μs	Ûw	kV	8	
Clearance distance (pri. -sec)	dCl	mm	12.9	Shortest distance through air
Creepage distance (pri. -sec)	dCp	mm	12.9	Shortest path along device body
Case material			V0	According to UL 94
Comparative tracking index	CTI	V	600	

2. Electrical parameters (STB-100LA/Z, STB-100LA/ZN)

Condition: Vcc = 5.0 V, RL = 10 kΩ, T A = 25℃, unless specified.

Parameters	Symbol	Unit	Min.	Typ.	Max.	Remark
Primary nominal rms current	I_pn	A		100		
Primary current measuring range	I_pm	A	-300		300	
Supply voltage	Vcc	V	4.75	5	5.25	
Consumption current	Ic	mA	15 + I_p/NS*1000			NS = 1500
Reference voltage	V_ref	V	2.48	2.5	2.52	
Electrical offset voltage	V_oe	mV		5		100 % tested (V_out – V_ref)@ 0 A
Magnetic offset current	I_om	A	100		100	@6*I_pn
Full-scale voltage	V_fs	V		± 0.625		(V_out – V_ref)@ I_pn
Theoretical sensitivity	G_th	mV/A		6.25		0.625 V @ I_pn
Sensitivity error	G_err	% of I_pn	-0.8		0.8	
Linearity error within I_pn	ξ_L	% of I_pn	-0.15		0.15	@25℃
Reaction time @ 10 % of I_p	t_ra	μs		0.3		
Step response time @ 90 % of I_p	t_r	μs		0.3		
-3 dB band width	BW	kHz		300		
Noise DC ~ 10 kHz DC ~ 100 kHz	Vnoise	mVpp		 5 6		
Accuracy @ 25℃	X	% of I_pn	-0.8		0.8	
Accuracy @ 85 °C	X_TRange	% of I_pn	-1.1		1.1	

3. Electrical parameters (STB-150LA/Z, STB-150LA/ZN)

Condition: Vcc = 5.0 V, RL = 10 kΩ, T A = 25℃, unless specified.

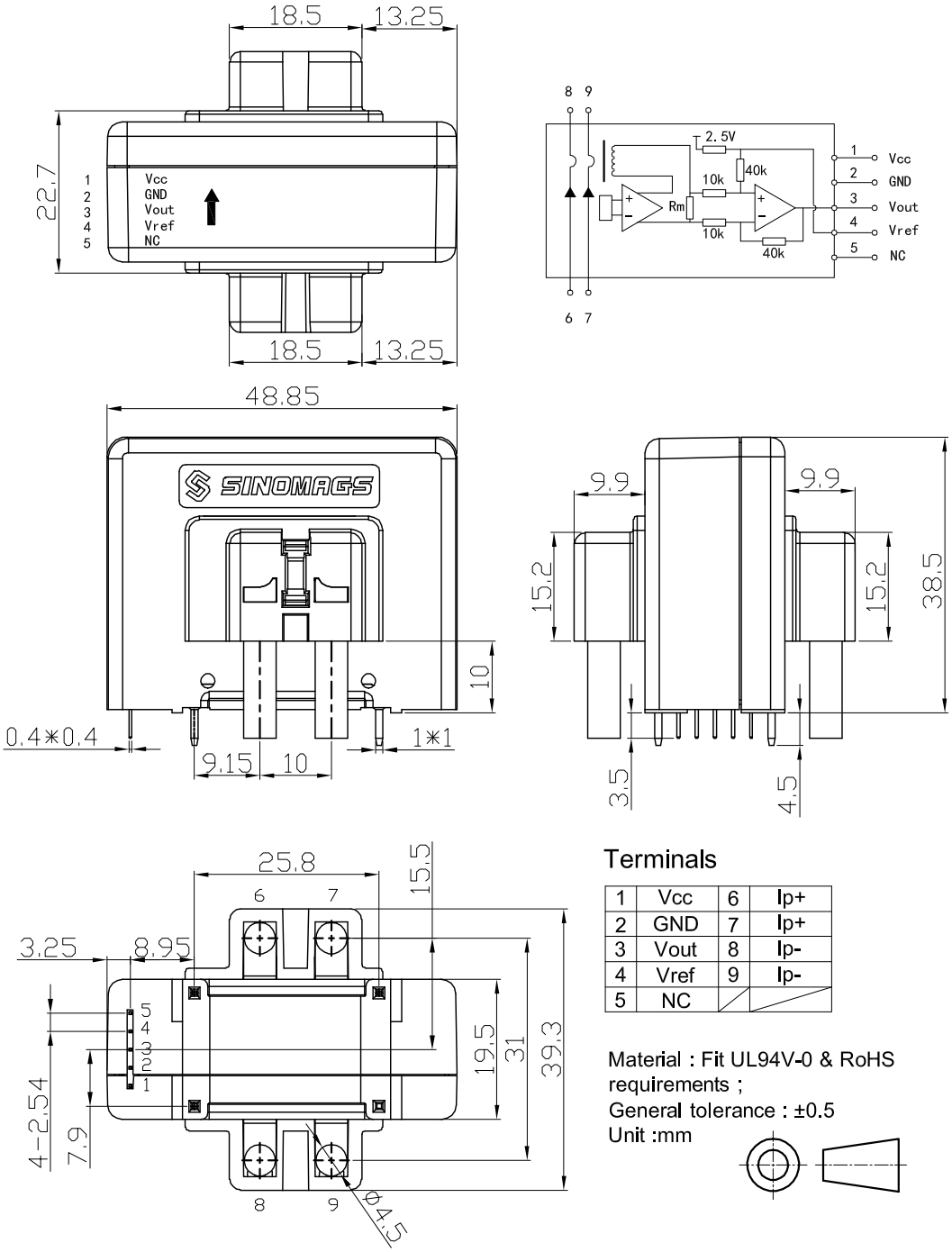
Parameters	Symbol	Unit	Min.	Typ.	Max.	Remark
Primary nominal rms current	I_pn	A		150		
Primary current measuring range	I_pm	A	-400		400	
Supply voltage	Vcc	V	4.75	5	5.25	
Consumption current	Ic	mA	15 + I_p/NS*1000			NS = 1500
Reference voltage	V_ref	V	2.48	2.5	2.52	
Electrical offset voltage	V_oe	mV		5		100 % tested (V_out – V_ref)@ 0 A
Magnetic offset current	I_om	mA	100		100	@6*I_pn
Full-scale voltage	V_fs	V		± 0.625		(V_out – V_ref)@ I_pn
Theoretical sensitivity	G_th	mV/A		4.167		0.625 V @ I_pn
Sensitivity error	G_err	% of I_pn	-0.8		0.8	
Linearity error within I_pn	ξ_L	% of I_pn	-0.15		0.15	@25℃
Reaction time @ 10 % of I_p	t_ra	μs		0.3		
Step response time @ 90 % of I_p	t_r	μs		0.3		
-3 dB band width	BW	kHz		300		
Noise DC ~ 10 kHz DC ~ 100 kHz	Vnoise	mVpp		 5 6		
Accuracy @ 25℃	X	% of I_pn	-0.8		0.8	
Accuracy @ 85 °C	X_TRange	% of I_pn	-1.1		1.1	

4. Electrical parameters (STB-200LA/Z, STB-200LA/ZN)

Condition: Vcc = 5.0 V, RL = 10 kΩ, T A = 25℃, unless specified.

Parameters	Symbol	Unit	Min.	Typ.	Max.	Remark
Primary nominal rms current	I_pn	A		200		
Primary current measuring range	I_pm	A	-450		450	
Supply voltage	Vcc	V	4.75	5	5.25	
Consumption current	Ic	mA	15 + I_p*/NS*1000			NS = 1500
Reference voltage	V_ref	V	2.48	2.5	2.52	
Electrical offset voltage	V_oe	mV		5		100 % tested (V_out – V_ref)@ 0 A
Magnetic offset current	I_om	mA	-210		210	@10*I_pn
Full-scale voltage	V_fs	V		± 0.625		(V_out – V_ref)@ I_pn
Theoretical sensitivity	G_th	mV/A		3.125		0.625 V @ I_pn
Sensitivity error	G_err	% of I_pn	-0.8		0.8	
Linearity error within I_pn	ξ_L	% of I_pn	-0.15		0.15	@25℃
Reaction time @ 10 % of I_p	t_ra	μs		0.3		
Step response time @ 90 % of I_p	t_r	μs		0.3		
-3 dB band width	BW	kHz		300		
Noise DC ~ 10 kHz DC ~ 100 kHz	Vnoise	mVpp		 5 6		
Accuracy @ 25℃	X	% of I_pn	-0.8		0.8	
Accuracy @ 85 °C	X_TRange	% of I_pn	-1.4		1.4	

5. Dimensions: STB-xxxLA/Z

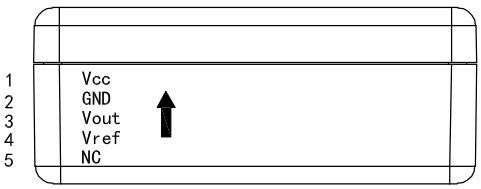


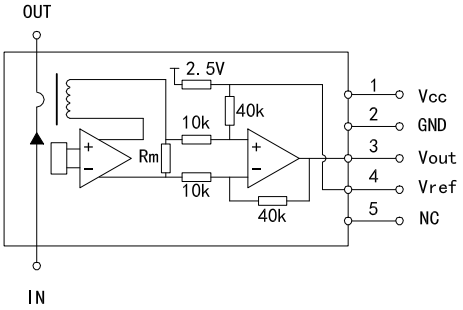
Terminals

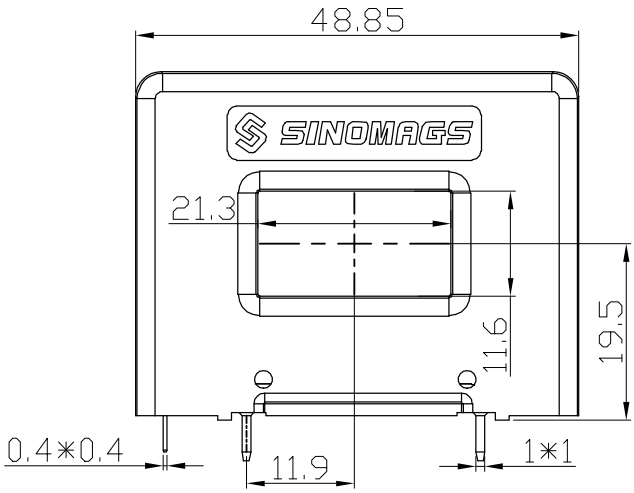
1	Vcc	6	Ip+
2	GND	7	Ip+
3	Vout	8	Ip-
4	Vref	9	Ip-
5	NC		

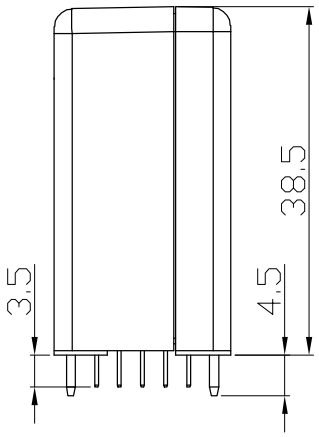
Material : Fit UL94V-0 & RoHS requirements ;
General tolerance : ±0.5
Unit :mm

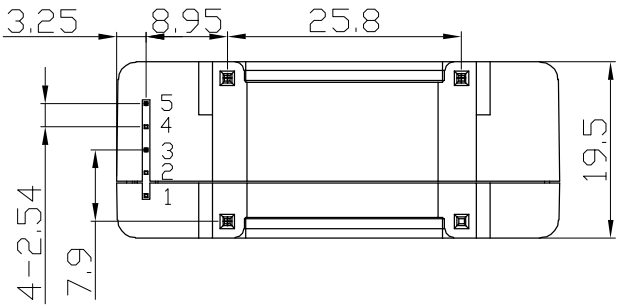
6. Dimensions: STB-xxxLA/ZN







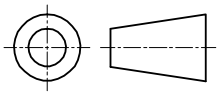




Terminals

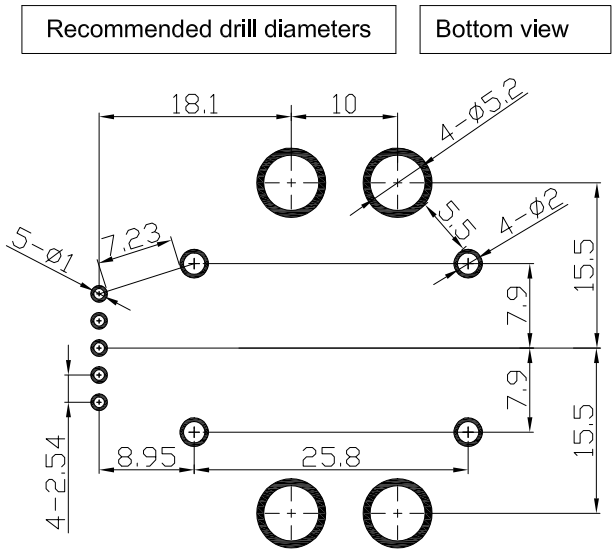
1	Vcc
2	GND
3	Vout
4	Vref
5	NC

Material : Fit UL94V-0 & RoHS requirements ;
General tolerance : ±0.5
Unit :mm



7. PCB footprint (STB-xxxLA/Z)

PCB holes diameters
Primary pins: Ø5.2mm
Secondary pins: Ø1.0mm
Retention pins: Ø2.0mm

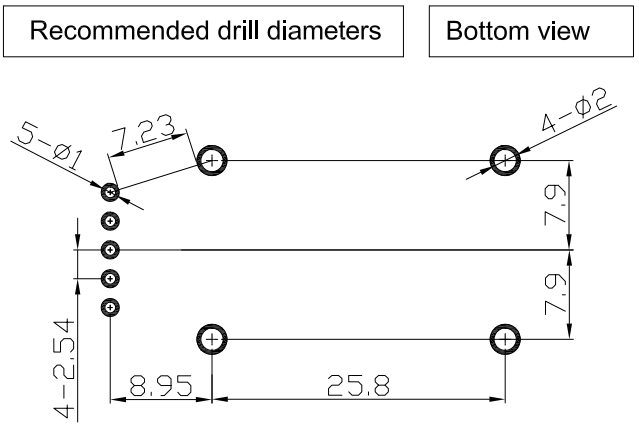


Assembly on PCB

- Recommended PCB hole diameter: 1 mm for secondary pins, 2 mm for retention pin.
- Maximum PCB thickness: 2.4 mm (can be customized per request).
- Wave soldering profile: maximum 260℃ for 10 seconds.

8. PCB footprint (STB-xxxLA/ZN)

PCB holes diameters
Secondary pins: Ø1.0mm
Retention pins: Ø2.0mm



Assembly on PCB

- Recommended PCB hole diameter: 1 mm for secondary pins, 2 mm for retention pin.
- Maximum PCB thickness: 2.4 mm (can be customized per request).
- Wave soldering profile: maximum 260℃ for 10 seconds.